

FMSBSS123

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FMSBSS123

100V N-Channel Enhancement Mode Power MOSFET

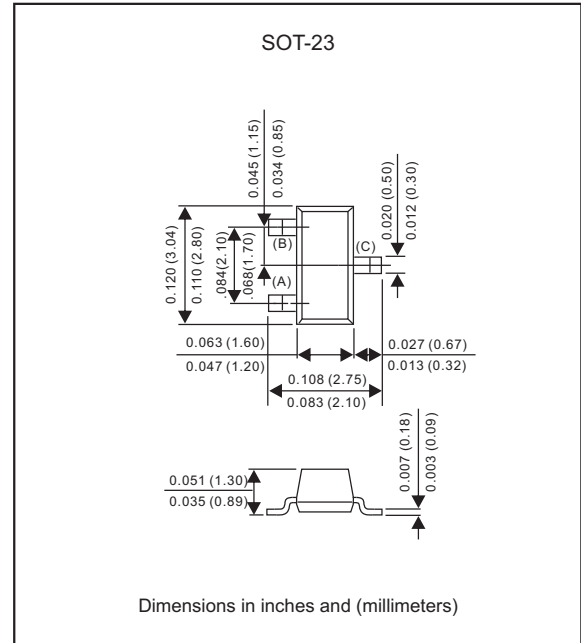
Package outline

Features

- Low on-resistance $R_{DS(ON)} = 6.0\Omega$
- Low input capacitance : 20pF
- Fast switching speed : 20ns
- Low output capacitance : 9pF
- Low threshold : 2.8V
- In compliance with EU RoHS 2002/95/EC directives
- Suffix "-H" indicates Halogen-free part, ex.FMSBSS123-H

Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, SOT-23
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Mounting Position : Any
- Weight : Approximated 0.008 gram



Maximum ratings (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	Symbol	MIN.	TYP.	MAX.	UNIT
Drain-source voltage	V_{DS}			100	Vdc
Drain current-Continuous *1	I_D			170	mAdc
-pulsed*2	I_{DM}			680	
Gate- source voltage-Continuous	V_{GS}			± 20	Vdc
Non-repetitive (tp \leq 50us)	V_{GSM}			± 40	Vpk
Total Device Dissipation FR-5 Board *3	P_D			225	mW
$T_A=25^\circ\text{C}$ Derate above 25°C				1.8	mW/ $^\circ\text{C}$
Typical Thermal resistance junction to ambient	$R_{\theta JA}$		556		$^\circ\text{C}/\text{W}$
Operation junction temperature	T_J	-55		+150	$^\circ\text{C}$
Storage temperature	T_{STG}	-55		+150	$^\circ\text{C}$

*1: The Power Dissipation of the package may result in a lower continuous drain current.

*2: Pulse Width \leq 300us, Duty Cycle \leq 2.0%

*3: FR-5=1.0x0.75x0.062 in.

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Electrical characteristics (At $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Off Characteristics						
Drain-source breakdown voltage	$V_{GS} = 0V, I_D = 250\mu\text{Adc}$	BV_{DSS}	100			Vdc
Zero gate voltage drain current	$V_{GS} = 0V, V_{DS} = 100Vdc, T_J = 25^\circ\text{C}$ $V_{GS} = 0V, V_{DS} = 100Vdc, T_J = 125^\circ\text{C}$	I_{DSS}			15 60	μAdc
Gate-body leakage current	$V_{GS} = 20Vdc, V_{DS} = 0$	I_{GSS}			50	nAdc
On Characteristics *4						
Gate threshold voltage	$V_{DS} = V_{GS}, I_D = 1.0\text{mAdc}$	$V_{GS(th)}$	0.8		2.8	Vdc
Static drain-source on-resistance	$V_{GS} = 10Vdc, I_D = 100\text{mAdc}$	$R_{DS(ON)}$		5.0	6.0	Ω
Forward transconductance	$V_{DS} = 25Vdc, I_D = 100\text{mAdc}$	g_{fs}	80			mmhos
Dynamic Characteristics						
Input capacitance	$V_{DS} = 25Vdc, V_{GS} = 0V,$ $f = 1.0\text{MHz}$	C_{iss}		20		μF
Output capacitance		C_{oss}		9.0		
Reverse transfer capacitance		C_{rss}		4.0		
Switching Characteristics *4						
Turn-On Delay Time	$V_{CC} = 30Vdc, R_{GS} = 50\Omega$ $I_C = 0.28\text{Adc}, V_{GS} = 10Vdc$	$t_{d(on)}$		20		ns
Turn-Off Delay Time		$t_{d(off)}$		40		
Reverse Diode						
Diode forward on-voltage	$V_{GS} = 0Vdc, I_D = 0.34\text{Adc}, T_J = 25^\circ\text{C},$	V_{SD}			1.3	V

*4: Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2.0\%$

Rating and characteristic curves (FMSBSS123)

FIG.1 OHMIC REGION

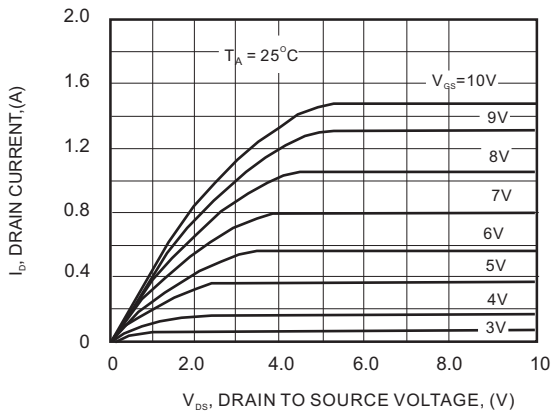


FIG.2 TRANSFER CHARACTERISTICS

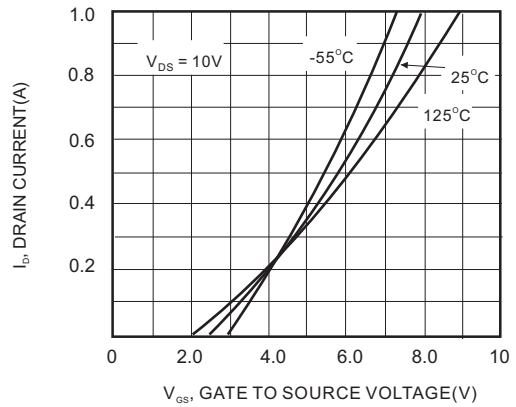


FIG.3 TEMPERATURE VS DRAIN-SOURCE ON-RESISTANCE

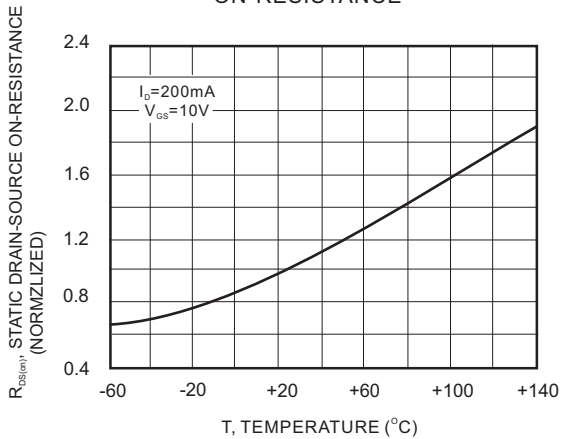
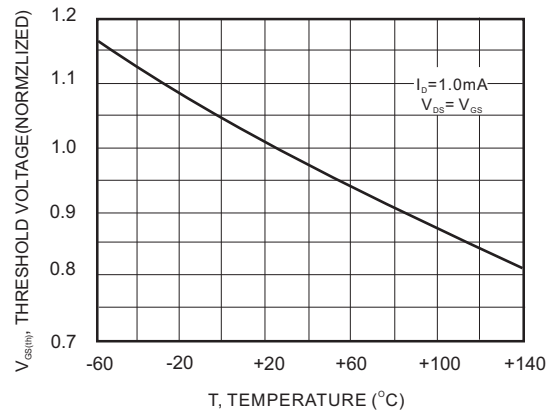
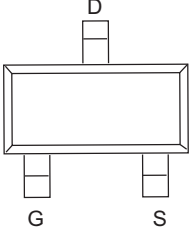
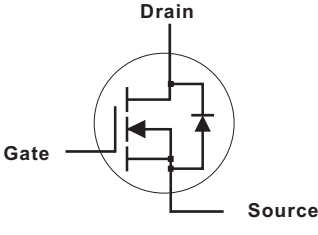


FIG.4 TEMPERATURE VS GATE THRESHOLD VOLTAGE



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Pinning information

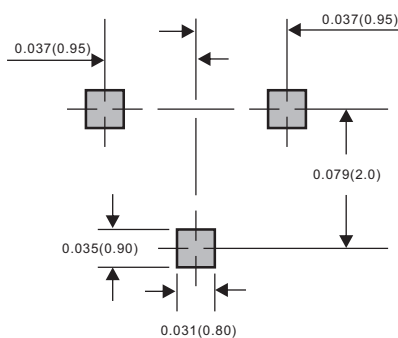
Pin	Simplified outline	Symbol
PinD Drain PinG Gate PinS Source		

Marking

Type number	Marking code
FMSBSS123	SA

Suggested solder pad layout

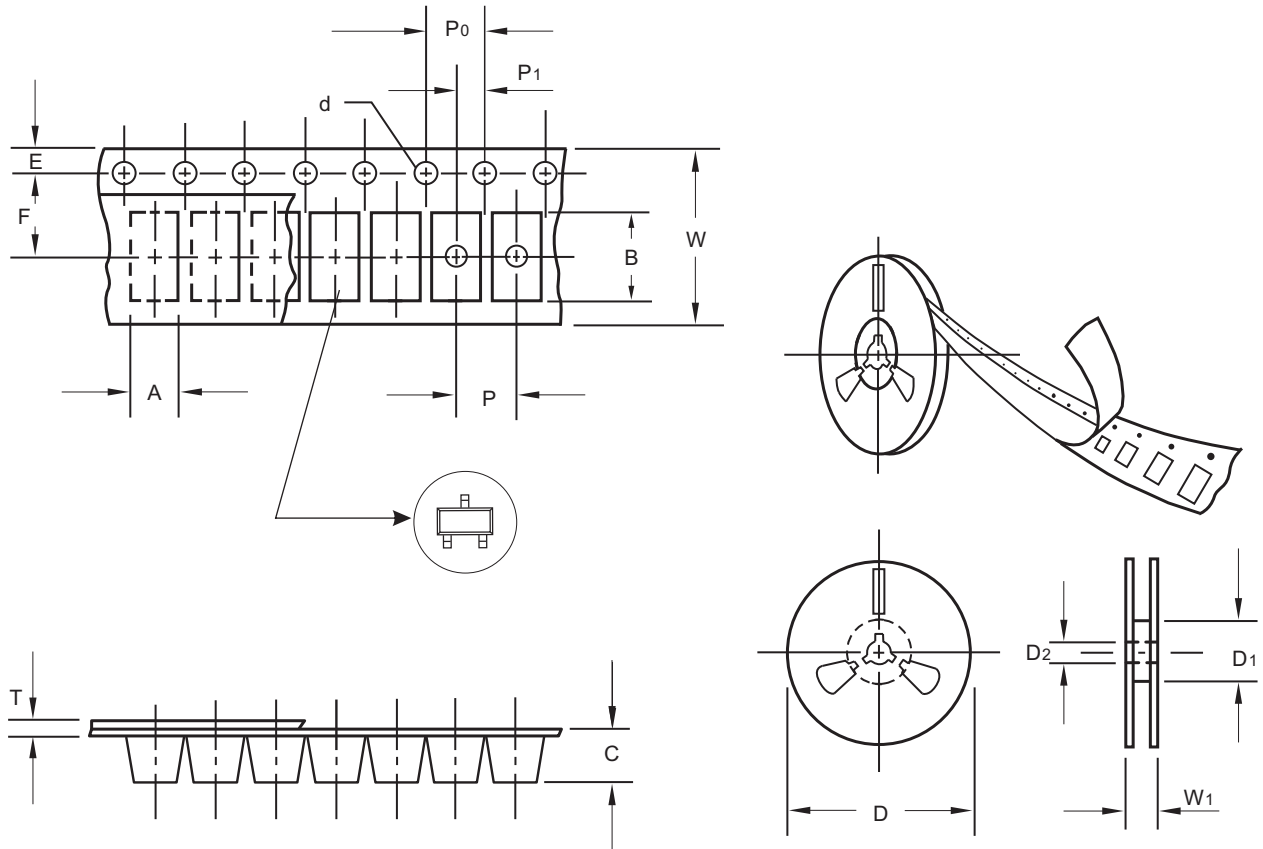
SOT-23



Dimensions in inches and (millimeters)

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Packing information



unit:mm

Item	Symbol	Tolerance	SOT-23
Carrier width	A	0.1	3.15
Carrier length	B	0.1	2.77
Carrier depth	C	0.1	1.22
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	-
13" Reel inner diameter	D1	min	-
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	55.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	8.00
Reel width	W1	1.0	12.0

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

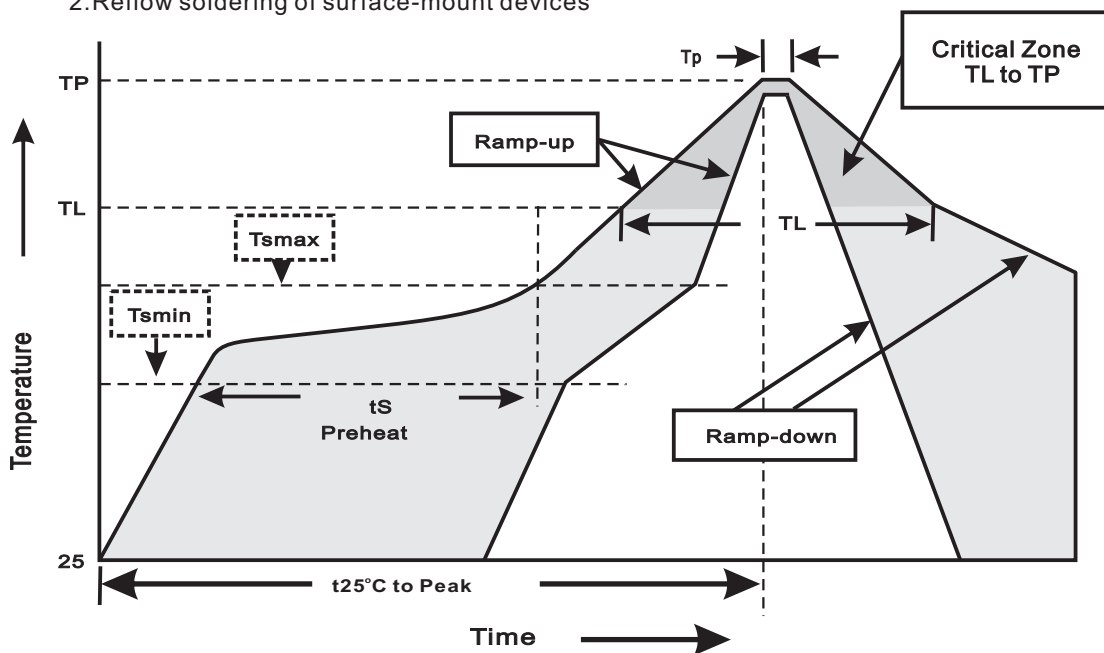
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Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOT-23	7"	3000	4.0	30,000	183*183*123	178	383*262*387	240,000	11.6

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T _L to T _P)	<3°C/sec
Preheat -Temperature Min(T _{min}) -Temperature Max(T _{max}) -Time(min to max)(t _s)	150°C 200°C 60~120sec
T _{max} to T _L -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T _L) -Time(t _L)	217°C 60~260sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t _P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes